



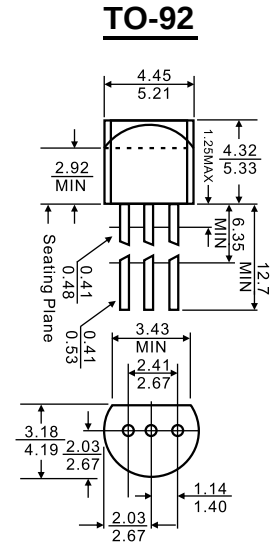
1. EMITTER
2. BASE
3. COLLECTOR

Features

- ✧ Power dissipation

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current -Continuous	600	mA
P_C	Collector Power dissipation	0.625	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55to +150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, junction to Ambient	357	$^\circ\text{C}/\text{mW}$



Dimensions in inches and (millimeters)

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}$, $I_E=0$	60		V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}$, $I_B=0$	40		V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}$, $I_C=0$	6		V
Collector cut-off current	I_{CBO}	$V_{CB}=35\text{V}$, $I_E=0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5\text{V}$, $I_C=0$		0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE}=1\text{V}$, $I_C=0.1\text{mA}$	20		
	$h_{FE(2)}$	$V_{CE}=1\text{V}$, $I_C=1\text{mA}$	40		
	$h_{FE(3)}$	$V_{CE}=1\text{V}$, $I_C=10\text{mA}$	80		
	$h_{FE(4)}$	$V_{CE}=1\text{V}$, $I_C=150\text{mA}$	100	300	
	$h_{FE(5)}$	$V_{CE}=2\text{V}$, $I_C=500\text{mA}$	40		
Collector-emitter saturation voltage	$V_{CE(sat)1}$	$I_C=150\text{mA}$, $I_B=15\text{mA}$		0.4	V
	$V_{CE(sat)2}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$		0.75	V
Base-emitter saturation voltage	$V_{BE(sat)1}$	$I_C=150\text{mA}$, $I_B=15\text{mA}$		0.95	V
	$V_{BE(sat)2}$	$I_C=500\text{mA}$, $I_B=50\text{mA}$		1.2	V
Transition frequency	f_T	$V_{CE}=10\text{V}$, $I_C=20\text{mA}$, $f=100\text{MHz}$	250		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=100\text{KHz}$		6.5	pF
Delay time	t_d	$V_{CC}=30\text{V}$, $V_{BE(OFF)}=2\text{V}$ $I_C=150\text{mA}$, $I_{B1}=15\text{mA}$		15	nS
Rise time	t_r			20	nS
Storage time	t_s	$V_{CC}=30\text{V}$, $I_C=150\text{mA}$ $I_{B1}=-I_{B2}=15\text{mA}$		225	nS
Fall time	t_f			30	nS

Typical Characteristics

